

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3288565	memory or storage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:40
L2	28970	1 and (magnetoresistive or magneto-resistive or magnetic) near4 (cell or element)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:41
L3	5667	2 and (cell or element) with parallel	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:42
L4	180	2 and (cell or element) with parallel with common\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:52
L5	15	2 and (cell or element) with parallel with common\$5 with gate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:50
L6	33	4 and processor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:50
L7	17	2 and (cell or element) with parallel with common\$5 with (bit adj line or bitline)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:52

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L1	3288565	memory or storage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:40
L2	28970	1 and (magnetoresistive or magneto-resistive or magnetic) near4 (cell or element)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:41
L3	5667	2 and (cell or element) with parallel	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:42
L4	180	2 and (cell or element) with parallel with common\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 18:08
L5	15	2 and (cell or element) with parallel with common\$5 with gate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:50
L6	33	4 and processor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 17:50
L7	17	2 and (cell or element) with parallel with common\$5 with (bit adj line or bitline)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 18:02
L9	10	2 and (cell or element) with parallel with different adj3 (voltage or potential otlevel)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 18:08

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	2	((memory or storage) and (magnetoresistive or magneto-resistive) and cell and parallel and common adj node and (transistor or switch\$5)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/27 18:35